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	APPLICATION NO.	FILING DATE	 FIRST NAMED IN	VENTOR	A	TORNEY DOCKET NO.
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					ART UNIT	PAPER NUMBER
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					DATE MAILED:	* * * * * * * * * * * * * * * * * * * *

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

	Application No.	Applicant(s)	
	09/046,671	TAKITA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Kurt M. Eaton	2823	
The MAILING DATE of this communication app Period for Reply	i .		
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, - Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	36(a). In no event, however, may a reply be within the statutory minimum of thirty (30) divil apply and will expire SIX (6) MONTHS fro cause the application to become ABANDON cause the application to become ABANDON	timely filed ays will be considered timely. m the mailing date of this communication	
1) Responsive to communication(s) filed on 14 N	May 2001 .		
	s action is non-final.		
3) Since this application is in condition for allowa closed in accordance with the practice under <i>B</i>	nce except for formal matters, Ex parte Quayle, 1935 C.D. 11,	prosecution as to the merits is 453 O.G. 213.	
Disposition of Claims			
4) Claim(s) 1-7 is/are pending in the application.			
4a) Of the above claim(s) is/are withdraw	vn from consideration.		
5) Claim(s) is/are allowed.			
6) Claim(s) <u>1-7</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/or	election requirement.		
Application Papers	·		
9)⊡ The specification is objected to by the Examiner			
10) ☐ The drawing(s) filed on is/are: a) ☐ accept		aminer.	
Applicant may not request that any objection to the			
11) The proposed drawing correction filed on			
If approved, corrected drawings are required in repl	ly to this Office action.		
12) The oath or declaration is objected to by the Exa	nminer.		
Priority under 35 U.S.C. §§ 119 and 120			
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)-(d) or (f).	
a) All b) Some * c) None of:			
1. Certified copies of the priority documents	have been received.		
2. Certified copies of the priority documents	have been received in Applicat	tion No	
3 Copies of the certified copies of the priori application from the International Bure * See the attached detailed Office action for a list of	eau (PCT Rule 17.2(a)).	Ç	
14) Acknowledgment is made of a claim for domestic	priority under 35 U.S C. § 119((e) (to a provisional application).	
a) The translation of the foreign language prov 15) Acknowledgment is made of a claim for domestic	* *		
ttachment(s)			
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 16	5) Notice of Informal	ry (PTO-413) Paper No(s) Patent Application (PTO-152)	
Patent and Trademark Office			

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DETAILED ACTION

Continued Prosecution Application

1. The request filed on 5/14/01 for a Continued Prosecution Application (CPA) under 37 CFR 1.53(d) based on parent Application No. 09/046,671 is acceptable and a CPA has been established. An action on the CPA follows.

Specification

2. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Rejections - 35 USC § 112

3. Claims 5-7 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Regarding claims 5-7, the phrase "and/or" renders the claim indefinite because it is unclear whether both the first and second semiconductor elements are memory cells or whether just one of the first and second semiconductor elements is a memory cell. The subject matter found within the claims must be written in a positive sense and the present alternative sense needs to be removed in order to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 5. Claims 1-4 are rejected under 35 U.S.C. 102(b) as being anticipated by Kenichi et al..

In re-claim 1, Kenichi et al. (herein referred to as Kenichi) shows in Figure 1 and related text a semiconductor device including: a lightly doped semiconductor substrate (1) of a first conduction type; a buried semiconductor layer (7) of a second conduction type formed in a first region of the semiconductor substrate; a semiconductor region (3/5) of the second conduction type extending from the surface of the semiconductor substrate to a peripheral portion of the buried semiconductor layer; and a semiconductor region (6) of the first conduction type formed in the semiconductor substrate surrounded by the buried semiconductor layer and the semiconductor region of the second conduction type, wherein a concentration of an impurity of the semiconductor region of the first conduction type is substantially equal to a concentration of an impurity of the semiconductor substrate.

In re-claim 2, Kenichi further includes a first semiconductor element formed in the first conduction type region; and a second semiconductor element formed in a second region different from the first region of the semiconductor substrate, wherein the first conduction type semiconductor region is connected to a first potential (V_{BB}) , and wherein the second region of the semiconductor substrate is connected to a second potential (V_{BB}) different from the first potential.

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In re claim 3, Kenichi, shows wherein the second conduction type semiconductor region is extended over a third region adjacent to the first region of the semiconductor substrate; wherein the semiconductor device further includes a third semiconductor element formed in the third region of the second conduction type semiconductor region; and wherein the second conduction type semiconductor region is connected to a third potential (V_{ss}) different at least from the first potential or the second potential.

In re-claim 4, Kenichi further includes a well of the first conduction type (2) formed in a fourth region in the third region; and a fourth semiconductor element formed in the first conduction type well, wherein the first conduction type well is connected to a fourth potential (V_{ext}) different from at least the first potential.

Claim Rejections - 35 USC § 103

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 5-7 are rejected under 35 U.S.C. 103(a) as being unparentable over Kenichi in view of Applicants admitted prior art.

In re-claims 5.7, Kenichi substantially discloses the invention as claimed but fails to show wherein the first semiconductor element and, or the second semiconductor element is a memory cell.

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Applicants admitted prior art shows in Figure 29A shows a semiconductor device essentially identical to that shown in Kenichi as applied to claims 1 and 2 in that Figure 29A shows a semiconductor device including: a lightly doped semiconductor substrate (114) of a first conduction type; a buried semiconductor layer (buried portion of 138) of a second conduction type formed in a first region of the semiconductor substrate, spaced from a surface of the semiconductor substrate; a semiconductor region (peripheral portions of 138 in contact with the surface of the semiconductor substrate) of the second conduction type extending from the surface of the semiconductor substrate to a peripheral portion of the buried semiconductor layer; and a semiconductor region (164) of the first conduction type formed in the semiconductor substrate surrounded by the buried semiconductor layer and the semiconductor region of the second conduction type, wherein the applicants admitted prior art further includes a first semiconductor clement. 152, 154) formed in the first conduction type region; and a second semiconductor element formed in a second region different from the first region of the semiconductor substrate, wherein the first conduction type semiconductor region is connected to a first potential (V_{ad}) , and wherein the second region of the semiconductor substrate is connected to a second potential different from the first potential. Applicants admitted prior art further teaches wherein the first semiconductor element and/or the second semiconductor element includes a memory cell {page 4, line 8 - page 8, line 3}.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to provide the first and, or second semiconductor element of Kenichi such that it included a memory cell sine coas evidenced by applicants admitted prior art, the inclusion of a memory cell in equivalent first and/or second semiconductor elements is well known in the art and the structural selection of a type of memory cell among any semiconductor elements available on the basis of its suitability for the intended use involves only routine skill in the art.

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Response to Arguments

8. Applicant's arguments with respect to claims 1-7 have been considered but are moot in view

of the new ground(s) of rejection.

Conclusion

9. Paper related to this application may be submitted directly to Art Unit 2823 by facsimile

transmission. Papers should be faxed to Art Unit 2823 via the Art Unit 2823 Fax Center located in

Crystal Plaza 4, room 4C23. The faxing of such papers must conform with the notice published in

the Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2823 Fax Center number is

(703) 308-7722 or -7724. The Art Unit 2823 has Center is to be used only for papers related to Art

Unit 2823 applications.

Any inquiry concerning this communication of earlier communication from the examiner

should be directed to Kurt Eaton at (703) 305-0383 and between the hours of 8:00 AM to 4:00 PM

(Eastern Standard Time) Monday through Friday or by e-mail via kurt.eaton@uspto.gov.

OLIK CHAUDHURI

SUPÉRVISURY PATÉNT EXAMINER

TECHNOLOGY CENTER 2800